# MMBFJ177LT1G

# **JFET Chopper**

# **P-Channel – Depletion**

### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Gate Voltage	V <sub>DG</sub>	25	Vdc
Reverse Gate-Source Voltage	V <sub>GS(r)</sub>	-25	Vdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### THERMAL CHARACTERISTICS

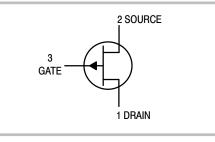
Total Device Dissipation FR-5 Board	PD	225	mW
(Note 1) T <sub>A</sub> = 25°C Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1. FR–5 = 1.0  $\times$  0.75  $\times$  0.062 in.



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**MARKING DIAGRAM** 



6Y = Specific Device Code

- M = Date Code\*
- = Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

Device	Device Package	
MMBFJ177LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBFJ177LT1G

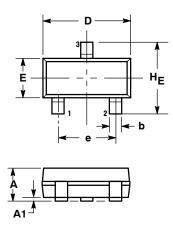
## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

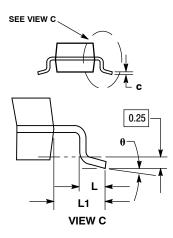
Chara	Symbol	Min	Мах	Unit	
OFF CHARACTERISTICS					
Gate-Source Breakdown Voltage (V <sub>DS</sub> =	V <sub>(BR)GSS</sub>	30	-	Vdc	
Gate Reverse Current ( $V_{DS}$ = 0 Vdc, $V_{GS}$	I <sub>GSS</sub>	-	1.0	nAdc	
Gate Source Cutoff Voltage (V <sub>DS</sub> = 15 Vo	V <sub>GS(off)</sub>	0.8	2.5	Vdc	
ON CHARACTERISTICS				-	•
Zero-Gate-Voltage Drain Current ( $V_{GS}$ =	I <sub>DSS</sub>	1.5	20	mAdc	
Drain Cutoff Current (V <sub>DS</sub> = 15 Vdc, V <sub>GS</sub>	I <sub>D(off)</sub>	-	1.0	nAdc	
Drain Source On Resistance ( $I_D = 500 \ \mu A$	r <sub>DS(on)</sub>	-	300	Ω	
Input Capacitance	V <sub>DS</sub> = 0, V <sub>GS</sub> = 10 Vdc	C <sub>iss</sub>	-	11	pF
Reverse Transfer Capacitance	f = 1.0 MHz	C <sub>rss</sub>	-	5.5	

2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty Cycle  $\leq$  2%.

### PACKAGE DIMENSIONS

SOT-23 (TO-236AB) CASE 318-08 **ISSUE AN** 





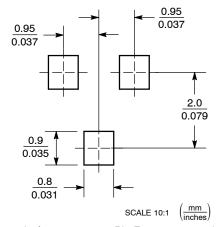
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF 3.
- BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW 4 STANDARD 318-08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 10: PIN 1. DRAIN 2. SOURCE З. GATE

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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